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2N5460, 2N5461, 2N5462

JFET Amplifier

P-Channel – Depletion

Features

- Pb-Free Packages are Available*

MAXIMUM RATINGS

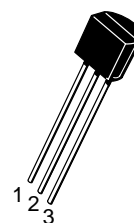
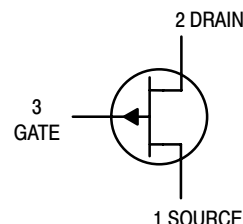
Rating	Symbol	Value	Unit
Drain – Gate Voltage	V_{DG}	40	Vdc
Reverse Gate – Source Voltage	V_{GSR}	40	Vdc
Forward Gate Current	$I_{G(f)}$	10	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	350 2.8	mW mW/ $^\circ\text{C}$
Junction Temperature Range	T_J	-65 to $+135$	$^\circ\text{C}$
Storage Channel Temperature Range	T_{stg}	-65 to $+150$	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



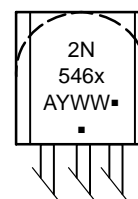
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**TO-92
CASE 29
STYLE 7**

MARKING DIAGRAM



2N546x = Device Code

x = 0, 1, or 2

A = Assembly Location

Y = Year

WW = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

2N5460, 2N5461, 2N5462

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS					
Gate–Source Breakdown Voltage ($I_G = 10\ \mu\text{Adc}$, $V_{DS} = 0$)	$V_{(BR)GSS}$	40	–	–	Vdc
Gate Reverse Current ($V_{GS} = 20\ \text{Vdc}$, $V_{DS} = 0$)	I_{GSS}	–	–	5.0	nAdc
($V_{GS} = 30\ \text{Vdc}$, $V_{DS} = 0$)		–	–	1.0	μAdc
($V_{GS} = 20\ \text{Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)		–	–	–	–
($V_{GS} = 30\ \text{Vdc}$, $V_{DS} = 0$, $T_A = 100^\circ\text{C}$)		–	–	–	–
Gate–Source Cutoff Voltage ($V_{DS} = 15\ \text{Vdc}$, $I_D = 1.0\ \mu\text{Adc}$)	$V_{GS(off)}$	0.75 1.0 1.8	– – –	6.0 7.5 9.0	Vdc
Gate–Source Voltage ($V_{DS} = 15\ \text{Vdc}$, $I_D = 0.1\ \text{mAdc}$)	V_{GS}	0.5	–	4.0	Vdc
($V_{DS} = 15\ \text{Vdc}$, $I_D = 0.2\ \text{mAdc}$)		0.8	–	4.5	
($V_{DS} = 15\ \text{Vdc}$, $I_D = 0.4\ \text{mAdc}$)		1.5	–	6.0	
ON CHARACTERISTICS					
Zero–Gate–Voltage Drain Current ($V_{DS} = 15\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{kHz}$)	I_{DSS}	–1.0 –2.0 –4.0	– – –	–5.0 –9.0 –16	mAdc
SMALL–SIGNAL CHARACTERISTICS					
Forward Transfer Admittance ($V_{DS} = 15\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{kHz}$)	$ y_{fs} $	1000 1500 2000	– – –	4000 5000 6000	μmhos
Output Admittance ($V_{DS} = 15\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{kHz}$)	$ y_{os} $	–	–	75	μmhos
Input Capacitance ($V_{DS} = 15\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{MHz}$)	C_{iss}	–	5.0	7.0	pF
Reverse Transfer Capacitance ($V_{DS} = 15\ \text{Vdc}$, $V_{GS} = 0$, $f = 1.0\ \text{MHz}$)	C_{rss}	–	1.0	2.0	pF
FUNCTIONAL CHARACTERISTICS					
Equivalent Short–Circuit Input Noise Voltage ($V_{DS} = 15\ \text{Vdc}$, $V_{GS} = 0$, $f = 100\ \text{Hz}$, BW = 1.0 Hz)	e_n	–	60	115	$\text{nV}/\sqrt{\text{Hz}}$

ORDERING INFORMATION

Device	Package	Shipping†
2N5460	TO–92	1000 Units / Box
2N5460G	TO–92 (Pb–Free)	
2N5461	TO–92	
2N5461G	TO–92 (Pb–Free)	
2N5461RLRA	TO–92	2000 / Tape & Reel
2N5461RLRAG	TO–92 (Pb–Free)	
2N5462	TO–92	1000 Units / Box
2N5462G	TO–92 (Pb–Free)	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**DRAIN CURRENT versus GATE
SOURCE VOLTAGE**

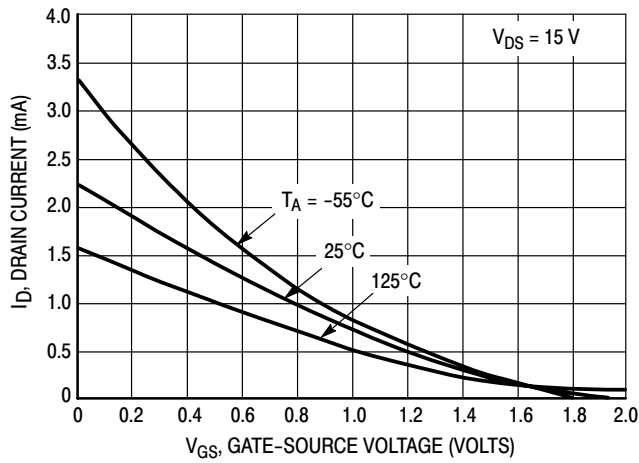


Figure 1. $V_{GS(off)} = 2.0$ V

**FORWARD TRANSFER ADMITTANCE
versus DRAIN CURRENT**

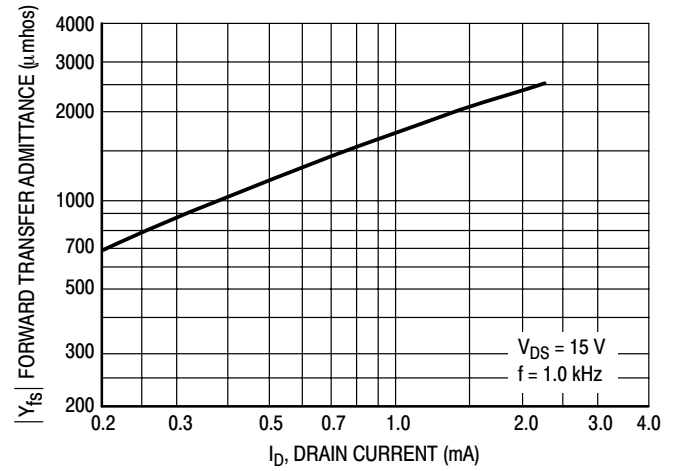


Figure 4. $V_{GS(off)} = 2.0$ V

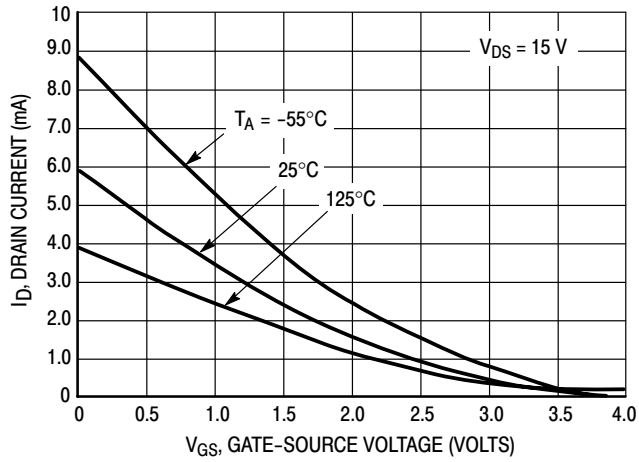


Figure 2. $V_{GS(off)} = 4.0$ V

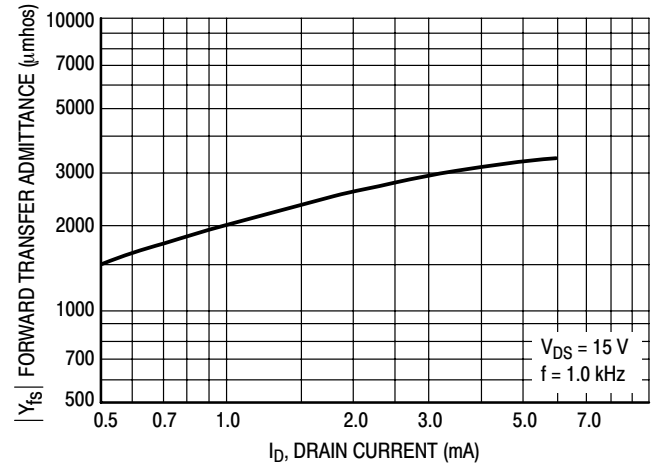


Figure 5. $V_{GS(off)} = 4.0$ V

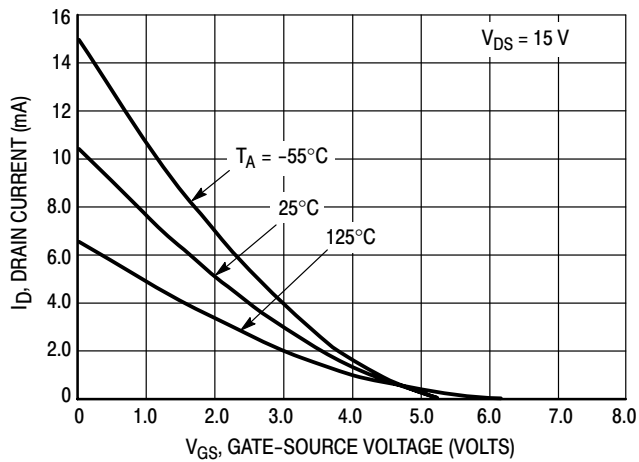


Figure 3. $V_{GS(off)} = 5.0$ V

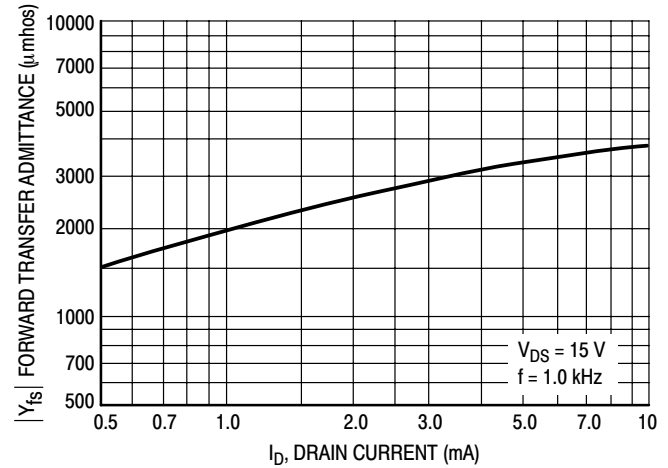


Figure 6. $V_{GS(off)} = 5.0$ V

2N5460, 2N5461, 2N5462

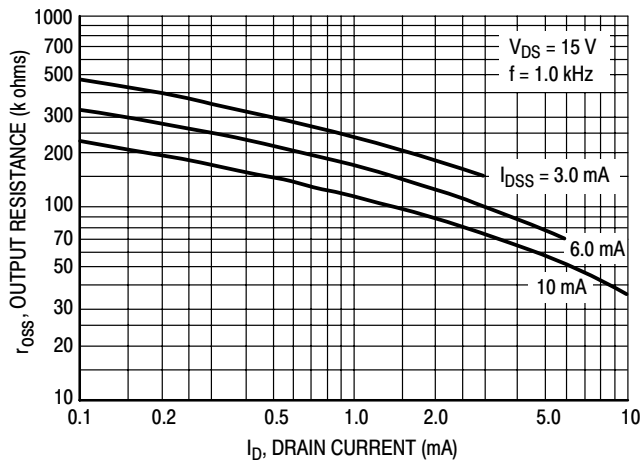


Figure 7. Output Resistance versus Drain Current

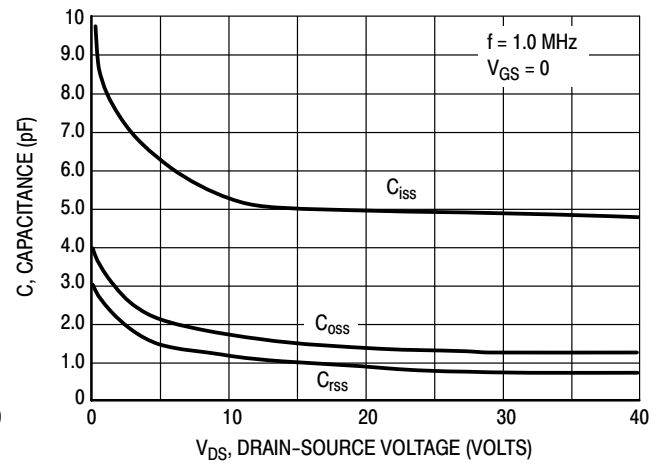


Figure 8. Capacitance versus Drain-Source Voltage

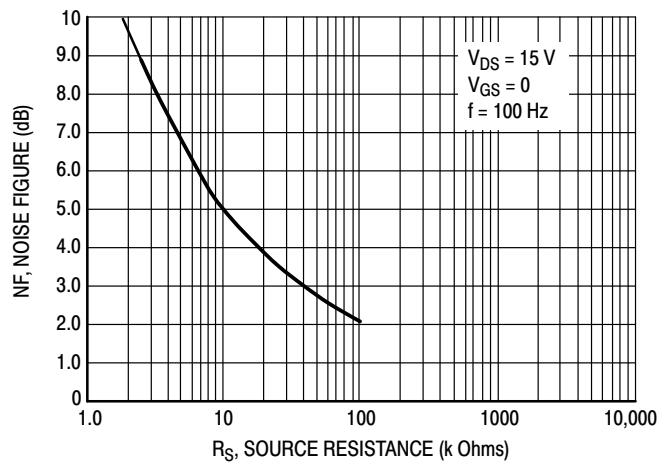
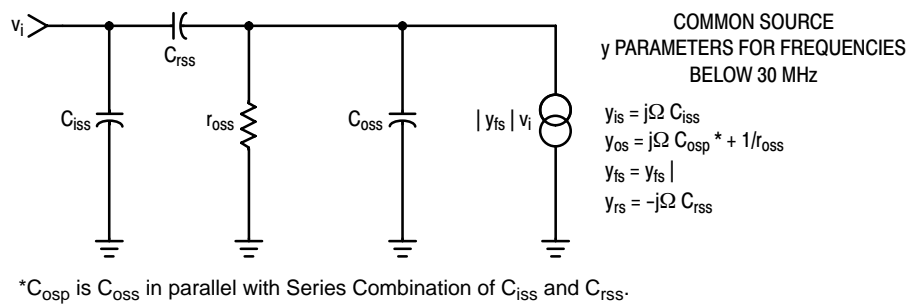


Figure 9. Noise Figure versus Source Resistance



NOTE:

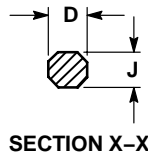
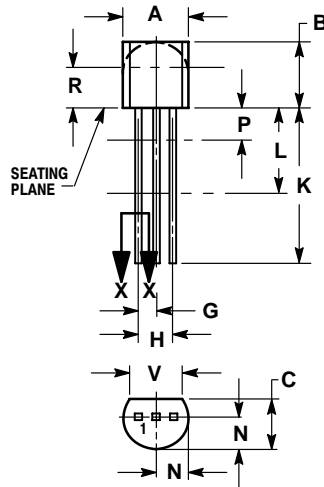
1. Graphical data is presented for dc conditions. Tabular data is given for pulsed conditions (Pulse Width = 630 ms, Duty Cycle = 10%).

Figure 10. Equivalent Low Frequency Circuit

2N5460, 2N5461, 2N5462

PACKAGE DIMENSIONS

TO-92
CASE 29-11
ISSUE AL




NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
E	0.045	0.055	1.15	1.39
F	0.095	0.105	2.42	2.66
G	0.015	0.020	0.39	0.50
H	0.500	---	12.70	---
I	0.250	---	6.35	---
J	0.080	0.105	2.04	2.66
K	---	0.100	---	2.54
L	0.115	---	2.93	---
M	0.135	---	3.43	---

STYLE 7:

1. SOURCE
2. DRAIN
3. GATE

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